# Supplementary information

# SnO<sub>2</sub>-supported single metal atoms: A Bifunctional Catalyst for the Electrochemical Synthesis of H<sub>2</sub>O<sub>2</sub>

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## **Computational details**

#### Calculation of absorption free energy

Catalytic activity of the SnO<sub>2</sub>- supported single metal atoms was assessed via binding energies of reaction intermediates involved in the 2e- WOR and ORR. Namely, adsorption free energies,  $\Delta G$ , of OH\* and OOH\* over two different surface-active sites (atop the single metal atom and on an adjacent Sn site) was explored.  $\Delta G$  was calculated at zero potential and pH=0, using the following equation:

 $\Delta G = \Delta E + \Delta Z P E - T \Delta S$ 

Where  $\Delta E$ ,  $\Delta ZPE$ , and  $\Delta S$  are adsorption energies with respect to water, zero-point energy difference and change in entropy, respectively.<sup>1</sup>

Additionally, the computational hydrogen electrode model (CHE) was implemented to calculate the free energy of all adsorbates. This approach assumes the chemical potential of a proton-electron pair to be equal to that of gas phase H<sub>2</sub> at  $U_{elec}$ =0.0 V vs. the reversible hydrogen electrode (RHE). By shifting the electron energy by -eU<sub>elec</sub> when e and U<sub>elec</sub> are the elementary charge and electrode potential, respectively, the effect of the electrode potential is taken into account.<sup>1</sup>

#### **Stability calculations**

Satability of SnO<sub>2</sub>- supported single metal atoms was investigated via formation energy calculations and resistance to dissolution. Formation energies were calculated through the following equation:<sup>2</sup>  $\Delta E_{form} = E_{M-Supp} - E_{M} - E_{Supp}$ 

Where  $E_{M-Supp}$ ,  $E_{M}$ ,  $E_{M-Supp}$  are electronic energies of metal-support complex, bulk metal atom and support materials, respectively. Dissoltion potential were calculated using the following:

$$U_{diss(Metal,SAC)} = U_{diss(Metal,Bulk)} - \frac{\mu_{Metal,SAC} - \mu_{Metal,Bulk}}{ne}$$

where  $U_{diss(Metal, Bulk)}$ ,  $\mu_{Metal, SAC}$ ,  $\mu_{Metal, Bulk}$ , and *n* are the dissolution potential of bulk metals, the chemical potential of metal atom in SAC system, that of bulk metal, and the number of electrons involved in the dissolution, respectively.  $\mu_{Metal, SAC}$  were calculated as  $E_{M-Supp.2,3}$ 

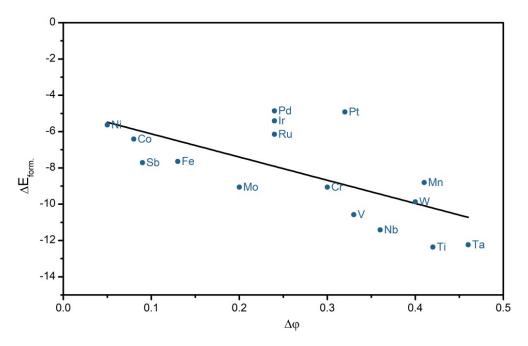
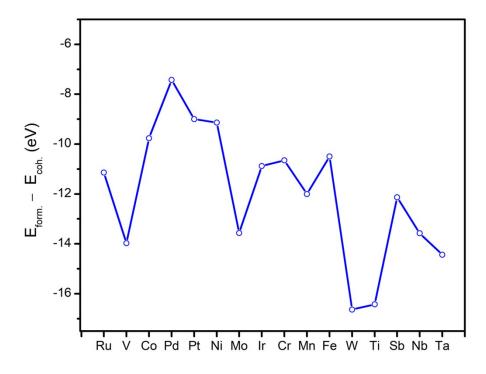
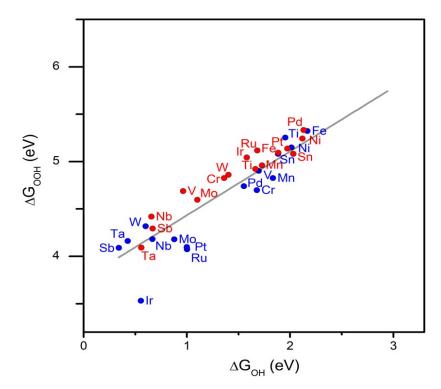


Figure 1.  $\Delta E_{form}$  of SnO<sub>2</sub>-supported single metal atoms as a function of the electronegativity

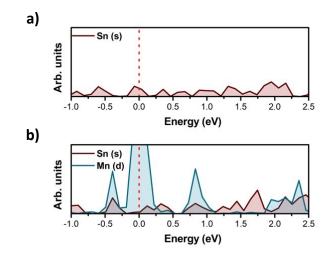


difference ( $\Delta \phi$ ) between Sn and single metal atom. Black line represents linear fit.

**Figure 2**. Difference between formation energy of the single metal with the SnO<sub>2</sub> support ( $E_{form.}$ ) and cohesive energy ( $E_{coh.}$ ) of the metal bulk.  $E_{coh.}$  values were obtained from ref. <sup>4,5</sup>



**Figure 3**. linear scaling relation between the Gibbs,  $\Delta G$ , free binding energies of OOH\* and OH\* intermediates. Blue data points show  $\Delta G$  when \*OH, and \*OOH intermediates are adsorbed on the surface of the single metal site, whereas red data points show DG of those adsorbed on the Sn site. Grey line represents linear fit.



**Figure 4.** Density of states for a) pure  $SnO_2$  and b) Mn: $SnO_2$ . The SAC increases the density of states at the fermi level and results in activating the  $SnO_2$  substrate and optimum interaction with the reaction intermediates.

### References

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